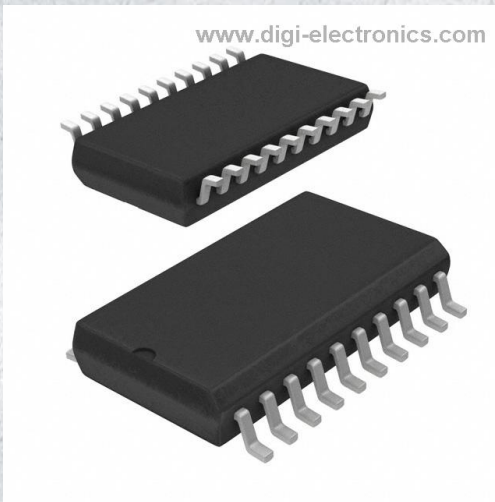


# 74LVX573MX Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	74LVX573MX-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	74LVX573MX
Description	IC D-TYPE TRANSP SGL 8:8 20SOIC
Detailed Description	D-Type Transparent Latch 1 Channel 8:8 IC Tri-State 20-SOIC



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

74LVX573MX

Series:

74LVX

Logic Type:

D-Type Transparent Latch

Output Type:

Tri-State

Independent Circuits:

1

Current - Output High, Low:

4mA, 4mA

Mounting Type:

Surface Mount

Supplier Device Package:

20-SOIC

Manufacturer:

onsemi

Product Status:

Obsolete

Circuit:

8:8

Voltage - Supply:

2V ~ 3.6V

Delay Time - Propagation:

5.9ns

Operating Temperature:

-40°C ~ 85°C

Package / Case:

20-SOIC (0.295", 7.50mm Width)

Base Product Number:

74LVX573

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8542.39.0001

Moisture Sensitivity Level (MSL):

1 (Unlimited)

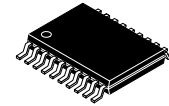
ECCN:

EAR99



# Low Voltage Octal Latch with 3-STATE Outputs

## 74LVX573


**TSSOP20, 4.4x6.5**  
**CASE 948AQ**

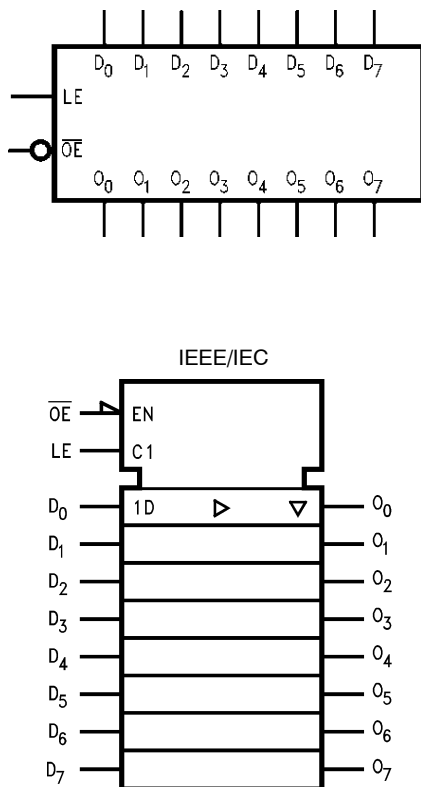
### General Description

The LVX573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable ( $\overline{OE}$ ) inputs. The LVX573 is functionally identical to the LVX373 but with inputs and outputs on opposite sides of the package. The inputs tolerate up to 5.5 V allowing interface of 5 V systems to 3 V systems.

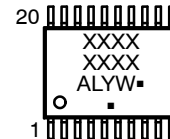
### Features

- Input Voltage Translation from 5 V to 3 V
- Ideal for Low Power / Low Noise 3.3 V Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- This is a Pb-Free Device

### Logic Symbol


**Figure 1. Logic Symbol**

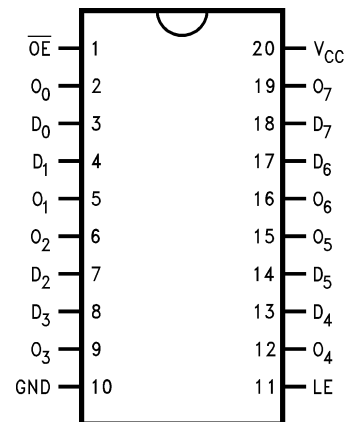
### MARKING DIAGRAM



XXXXXX = Specific Device Code  
 A = Assembly Location  
 L = Wafer Lot  
 Y = Year  
 W = Work Week  
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

### CONNECTION DIAGRAM



### PIN DESCRIPTION

Pin Names	Description
D <sub>0</sub> – D <sub>7</sub>	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	Output Enable Input
O <sub>0</sub> – O <sub>7</sub>	3-STATE Outputs

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

**74LVX573****Functional Description**

The LVX573 contains eight D-type latches. When the enable (LE) input is HIGH, data on the D<sub>n</sub> inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ( $\overline{OE}$ ) input. When  $\overline{OE}$  is LOW, the buffers are enabled. When  $\overline{OE}$  is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

**TRUTH TABLE**

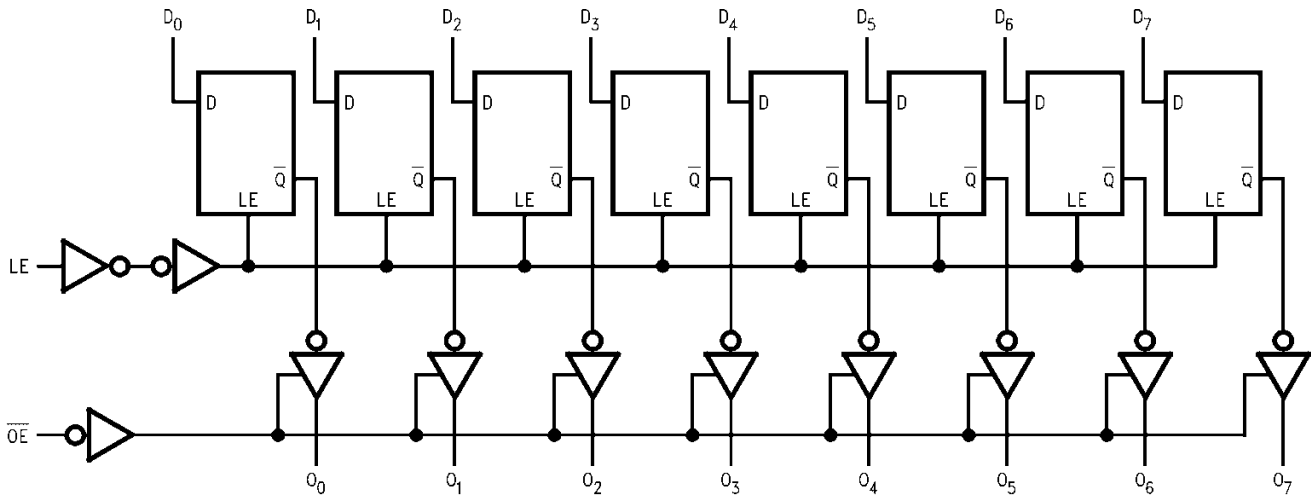
Inputs			Outputs
$\overline{OE}$	LE	D	O <sub>n</sub>
L	H	H	H
L	H	L	L
L	L	X	O <sub>0</sub>
H	X	X	Z

H = HIGH Voltage

L = LOW Voltage

Z = High Impedance

X = Immaterial

O<sub>0</sub> = Previous O<sub>0</sub> before HIGH-to-LOW transition of Latch Enable**Logic Diagram**

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

**Figure 2. Logic Diagram**

**74LVX573****MAXIMUM RATINGS**

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage		-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IN</sub>	DC Input Current, per Pin		±20	mA
I <sub>OUT</sub>	DC Output Current, per Pin		±25	mA
I <sub>CC</sub>	DC Supply Current, V <sub>CC</sub> and GND Pins		±75	mA
I <sub>IK</sub>	Input Clamp Current		-20	mA
I <sub>OK</sub>	Output Clamp Current		±20	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T <sub>J</sub>	Junction Temperature Under Bias		+150	°C
θ <sub>JA</sub>	Thermal Resistance (Note 2)	SOIC-20W	96	°C/W
		TSSOP-20	150	
P <sub>D</sub>	Power Dissipation in Still Air at 25 °C	SOIC-20W	1302	mW
		TSSOP-20	833	
MSL	Moisture Sensitivity	SOIC-20W	Level 3	-
		All Other Packages	Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.573 in	-
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V
		Charged Device Model	N/A	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

**RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage	2.0	3.6	V
V <sub>IN</sub>	DC Input Voltage (Note 4)	0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (Note 4)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Rate	0	100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

## 74LVX573

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V <sub>CC</sub>	T <sub>A</sub> = 25 °C			T <sub>A</sub> = -40 °C to +85 °C		Unit	
				Min	Typ	Max	Min	Max		
V <sub>IH</sub>	HIGH Level Input Voltage		2.0	1.5	-	-	1.5	-	V	
			3.0	2.0	-	-	2.0	-		
			3.6	2.4	-	-	2.4	-		
V <sub>IL</sub>	LOW Level Input Voltage		2.0	-	-	0.5	-	0.5	V	
			3.0	-	-	0.8	-	0.8		
			3.6	-	-	0.8	-	0.8		
V <sub>OH</sub>	HIGH Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	-	1.9	-	V
			I <sub>OH</sub> = -50 μA	3.0	2.9	3.0	-	2.9	-	
			I <sub>OH</sub> = -4 mA	3.0	2.58	-	-	2.48	-	
V <sub>OL</sub>	LOW Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	-	0.0	0.1	-	0.1	V
			I <sub>OL</sub> = 50 μA	3.0	-	0.0	0.1	-	0.1	
			I <sub>OL</sub> = 4 mA	3.0	-	-	0.36	-	0.44	
I <sub>OZ</sub>	3-STATE Output Off-State Current	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>OUT</sub> = V <sub>CC</sub> or GND	3.6	-	-	±0.25	-	±2.5	μA	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	3.6	-	-	±0.1	-	±1.0	μA	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6	-	-	4.0	-	40.0	μA	

## NOISE CHARACTERISTICS (Note 5)

Symbol	Parameter	C <sub>L</sub> (pF)	V <sub>CC</sub> (V)	T <sub>A</sub> = 25 °C		Unit
				Typ	Limits	
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	50	3.3	0.5	0.8	V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	50	3.3	-0.5	-0.8	V
V <sub>IHD</sub>	Minimum HIGH Level Dynamic Input Voltage	50	3.3	-	2.0	V
V <sub>ILD</sub>	Maximum LOW Level Dynamic Input Voltage	50	3.3	-	0.8	V

5. (Input t<sub>r</sub> = t<sub>f</sub> = 3 ns)

## 74LVX573

## AC ELECTRICAL CHARACTERISTICS

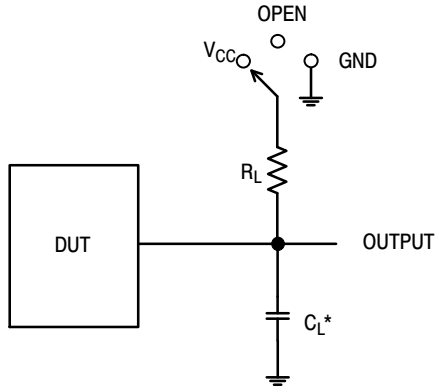
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25 °C			T <sub>A</sub> = -40 °C to +85 °C		Unit
				Min	Typ	Max	Min	Max	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay Time (D <sub>n</sub> to O <sub>n</sub> )	C <sub>L</sub> = 15 pF	2.7	-	7.6	14.5	1.0	17.5	ns
				C <sub>L</sub> = 50 pF	-	10.1	18.0	1.0	
		C <sub>L</sub> = 15 pF	3.3 ±0.3	-	5.9	9.3	1.0	11.0	ns
				C <sub>L</sub> = 50 pF	-	8.4	12.8	1.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay Time (LE to O <sub>n</sub> )	C <sub>L</sub> = 15 pF	2.7	-	8.2	15.6	1.0	18.5	ns
				C <sub>L</sub> = 50 pF	-	10.7	19.1	1.0	
		C <sub>L</sub> = 15 pF	3.3 ±0.3	-	6.4	10.1	1.0	12.0	ns
				C <sub>L</sub> = 50 pF	-	8.9	13.6	1.0	
t <sub>PZL</sub> , t <sub>PZH</sub>	3-STATE Output Enable Time	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 1 kΩ	2.7	-	7.8	15.0	1.0	18.5	ns
				C <sub>L</sub> = 50 pF R <sub>L</sub> = 1 kΩ	-	10.3	18.5	1.0	
		C <sub>L</sub> = 15 pF R <sub>L</sub> = 1 kΩ	3.3 ±0.3	-	6.1	9.7	1.0	12.0	ns
				C <sub>L</sub> = 50 pF R <sub>L</sub> = 1 kΩ	-	8.6	13.2	1.0	
t <sub>PLZ</sub> , t <sub>PHZ</sub>	3-STATE Output Disable Time	C <sub>L</sub> = 50 pF R <sub>L</sub> = 1 kΩ	2.7	-	12.1	19.1	1.0	22.0	ns
				C <sub>L</sub> = 50 pF R <sub>L</sub> = 1 kΩ	3.3 ±0.3	-	10.1	13.6	
t <sub>W</sub>	LE Pulse Width		2.7	6.5	-	-	7.5	-	ns
			3.3 ±0.3	5.0	-	-	5.0	-	
t <sub>S</sub>	Setup Time (D <sub>n</sub> to LE)		2.7	5.0	-	-	5.0	-	ns
			3.3 ±0.3	3.5	-	-	3.5	-	
t <sub>H</sub>	Hold Time (D <sub>n</sub> to LE)		2.7	1.5	-	-	1.5	-	ns
			3.3 ±0.3	1.5	-	-	1.5	-	
t <sub>OSLH</sub> , t <sub>OSSL</sub>	Output to Output Skew (Note 6)	C <sub>L</sub> = 50 pF	2.7	-	-	1.5	-	1.5	ns
			2.3	-	-	1.5	-	1.5	

6. Parameter guaranteed by design. t<sub>OSLH</sub> = |t<sub>PLHm</sub> - t<sub>PLHn</sub>|; t<sub>OSSL</sub> = |t<sub>PHLm</sub> - t<sub>PHLn</sub>|

## CAPACITANCE

Symbol	Parameter	T <sub>A</sub> = 25 °C			T <sub>A</sub> = -40 °C to +85 °C		Unit
		Min	Typ	Max	Min	Max	
C <sub>IN</sub>	Input Capacitance	-	4	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	-	6	-	-	-	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 7)	-	27	-	-	-	pF

7. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC</sub> (opr.) = C<sub>PD</sub> · V<sub>CC</sub> · f<sub>IN</sub> + I<sub>CC</sub> / 8 (per Latch).

**74LVX573****TEST CIRCUITS**

\* $C_L$  includes probe and jig capacitance  
 Input  $t_R = t_F = 3$  ns

Test	Switch Position	$C_L$	$R_L$
$t_{PLH} / t_{PHL}$	Open	See AC Characteristics Table	1 k $\Omega$
$t_{PLZ} / t_{PZL}$	$V_{CC}$		
$t_{PHZ} / t_{PZH}$	GND		

**Figure 3. AC Test Circuit**

**ORDERING INFORMATION**

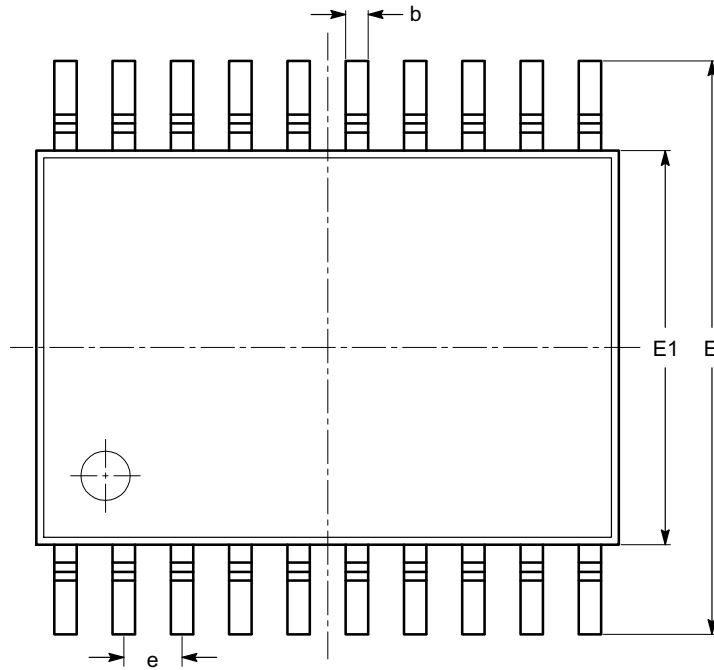
Device	Marking	Package	Shipping <sup>†</sup>
74LVX573MTCX	LVX 573	TSSOP-20	2500 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



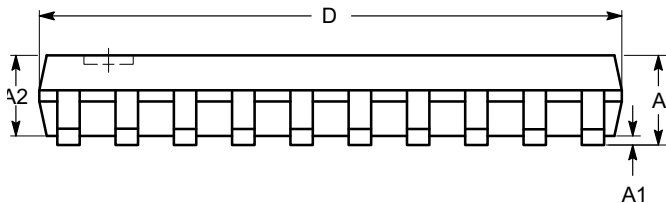
**TSSOP20, 4.4x6.5**  
**CASE 948AQ**  
**ISSUE A**

DATE 19 MAR 2009

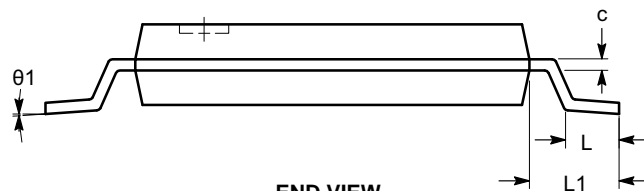


TOP VIEW

SYMBOL	MIN	NOM	MAX
A			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
c	0.09		0.20
D	6.40	6.50	6.60
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
$\theta$	0°		8°



SIDE VIEW



END VIEW

**Notes:**

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

<b>DOCUMENT NUMBER:</b>	<b>98AON34453E</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>TSSOP20, 4.4X6.5</b>	<b>PAGE 1 OF 1</b>

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

**TECHNICAL PUBLICATIONS:**

Technical Library: [www.onsemi.com/design/resources/technical-documentation](http://www.onsemi.com/design/resources/technical-documentation)  
onsemi Website: [www.onsemi.com](http://www.onsemi.com)

**ONLINE SUPPORT:** [www.onsemi.com/support](http://www.onsemi.com/support)

For additional information, please contact your local Sales Representative at [www.onsemi.com/support/sales](http://www.onsemi.com/support/sales)

## OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we stricly control the quality of products and services. Welcome your RFQ to

Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.